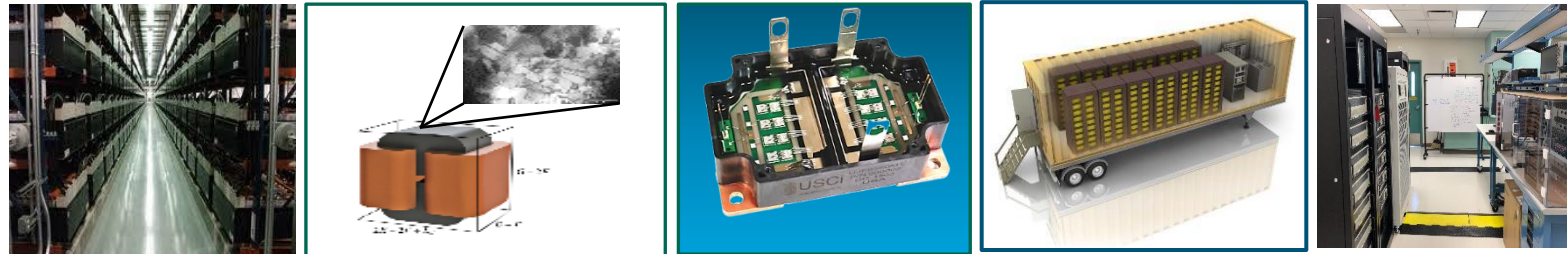




ENERGY STORAGE POWER ELECTRONICS PROGRAM



PRESENTED BY

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ENERGY STORAGE R&D AT SANDIA



BATTERY MATERIALS

Large portfolio of R&D projects related to advanced materials, new battery chemistries, electrolyte materials, and membranes.



CELL & MODULE LEVEL SAFETY

Evaluate safety and performance of electrical energy storage systems down to the module and cell level.



POWER CONVERSION SYSTEMS

Research and development regarding reliability and performance of power electronics and power conversion systems.



SYSTEMS ANALYSIS

Test laboratories evaluate and optimize performance of megawatt-hour class energy storage systems in grid-tied applications.



DEMONSTRATION PROJECTS

Work with industry to develop, install, commission, and operate electrical energy storage systems.



STRATEGIC OUTREACH

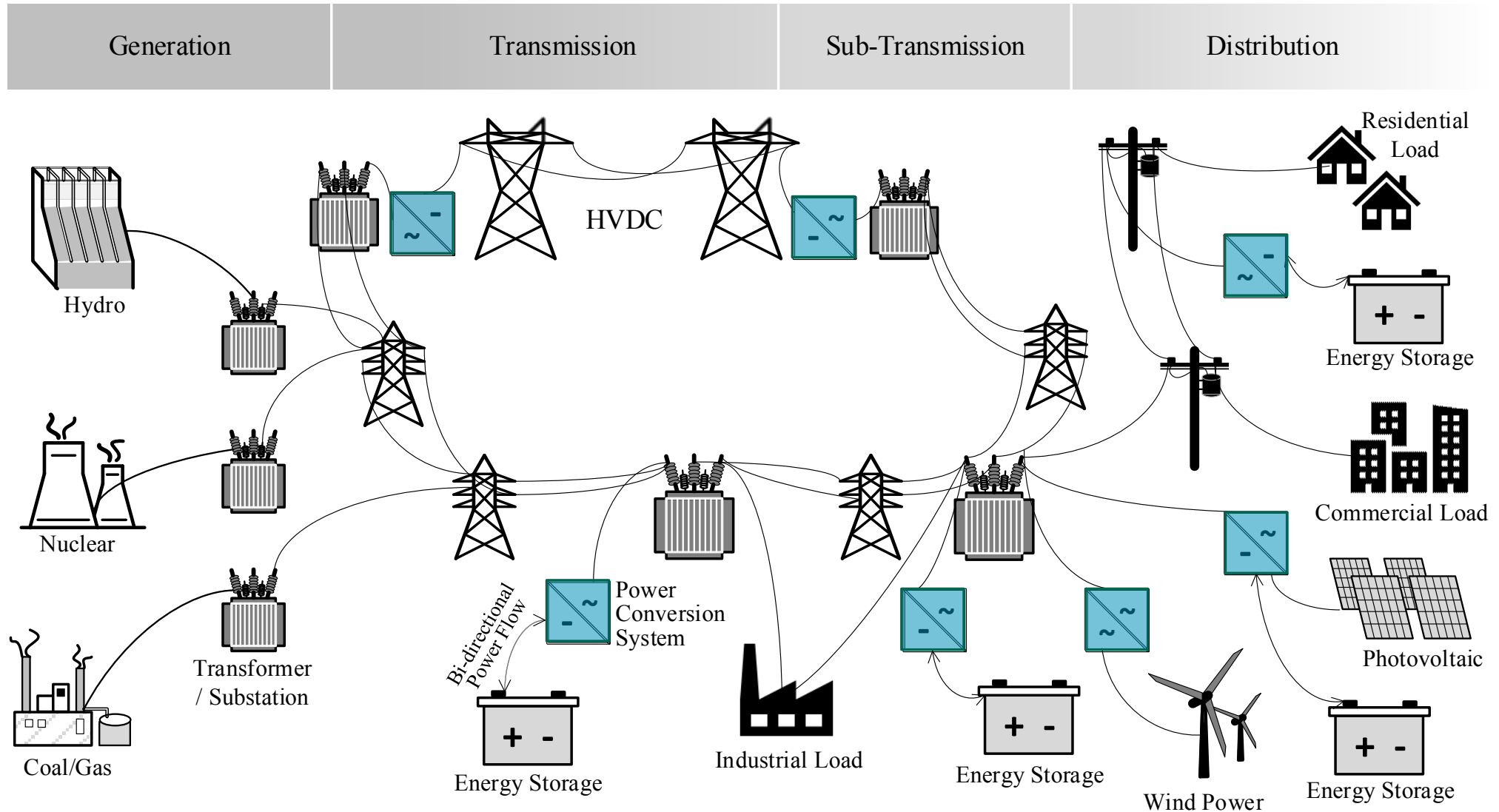
Maintain the ESS website and DOE Global Energy Storage Database, organize the annual Peer Review meeting, and host webinars and conferences.



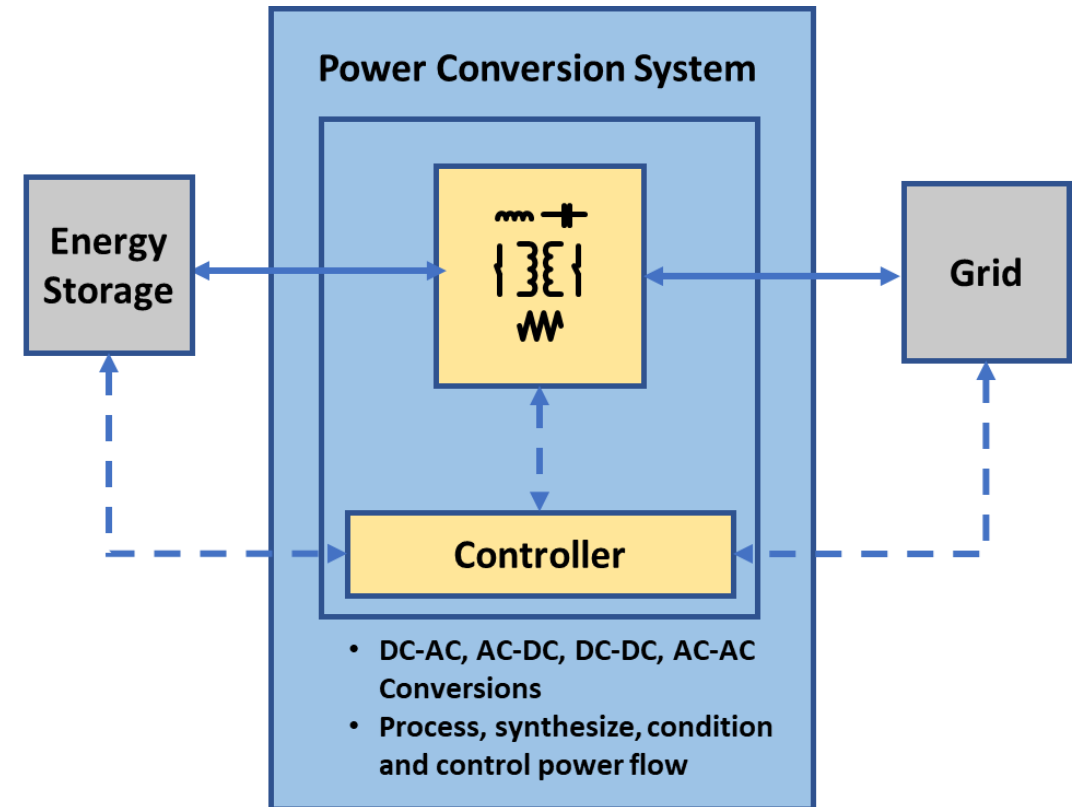
GRID ANALYTICS

Analytical tools model electric grids and microgrids, perform system optimization, plan efficient utilization and optimization of DER on the grid, and understand ROI of energy storage.

Wide ranging R&D covering energy storage technologies with applications in the grid, transportation, and stationary storage



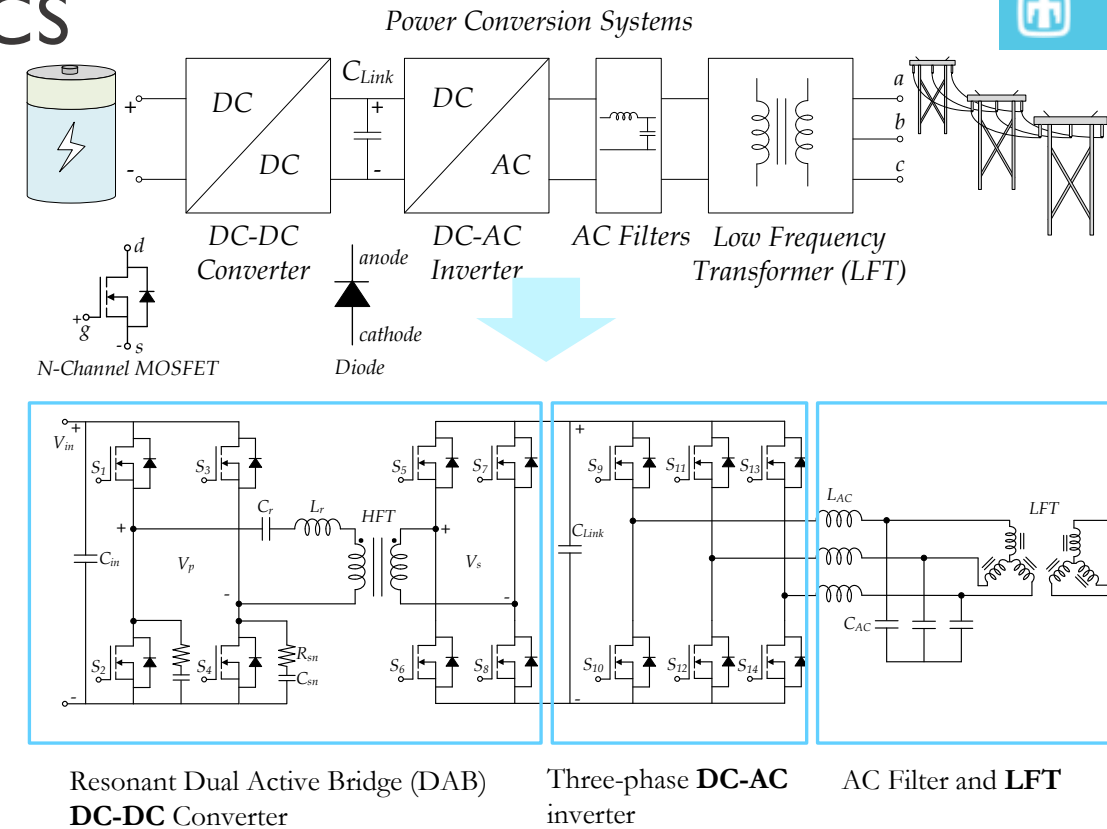
- Power conversion systems (PCS), sometimes referred to and used interchangeably as power electronics, are a key enabling technology for energy storage.
- In a grid-tied energy storage system, the PCS controls the power supplied to and absorbed from the grid, simultaneously optimizing energy storage device performance and maintaining grid stability.
- There are multiple types of energy storage technologies, and each has their own characteristics and control parameters that must be managed by the PCS.
- An energy storage installation may be tasked with a variety of different grid support services; the PCS is responsible for controlling the flow of energy to meet the requirements of the intended grid support application.
- The major electrical components of a PCS are semiconductor switches, magnetic devices such as inductors and transformers, capacitors, and a controller.



ROLE OF SEMICONDUCTORS IN PCS

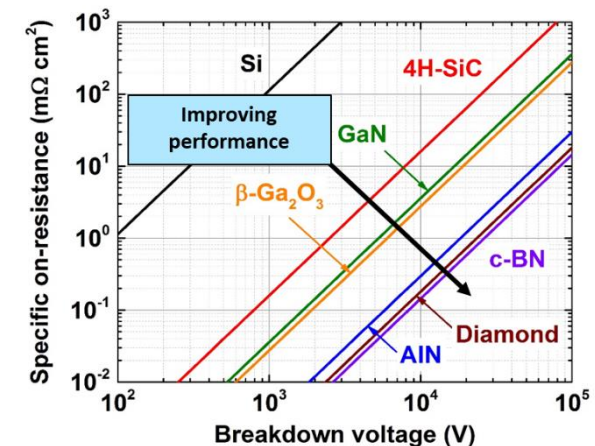
Semiconductor devices such as transistors and diodes are electronic components that rely on the internal material such as silicon for its function. For example:

- Transistors can become an open or short circuit based on the voltage level between the gate and source terminals. For a N-channel MOSFET, $v_{gs} > V_{th}$ turns ON the device.
- Diodes conduct only when there is a positive voltage between the anode and cathode terminals.
- Typically, semiconductor devices are made from Silicon (Si), but new wide bandgap (WBG) materials—such as Silicon Carbide (SiC) and Gallium Nitride (GaN)—are known for higher switching frequencies, higher blocking voltages, lower switching losses and higher junction temperatures than silicon-based switches.
 - SiC (High Power): 650 V +
 - GaN (Low Power): < 650 V, > 900V in development
- Reliability remains one of the major factors impeding the widespread adoption of WBG power devices; need to design, fabricate, and characterize WBG devices as a neutral third party.
- Battery electric vehicles will drive volumes up, cost down, and reliability up in the next 10 years.
- Electric grid is additional performance/reliability driver.



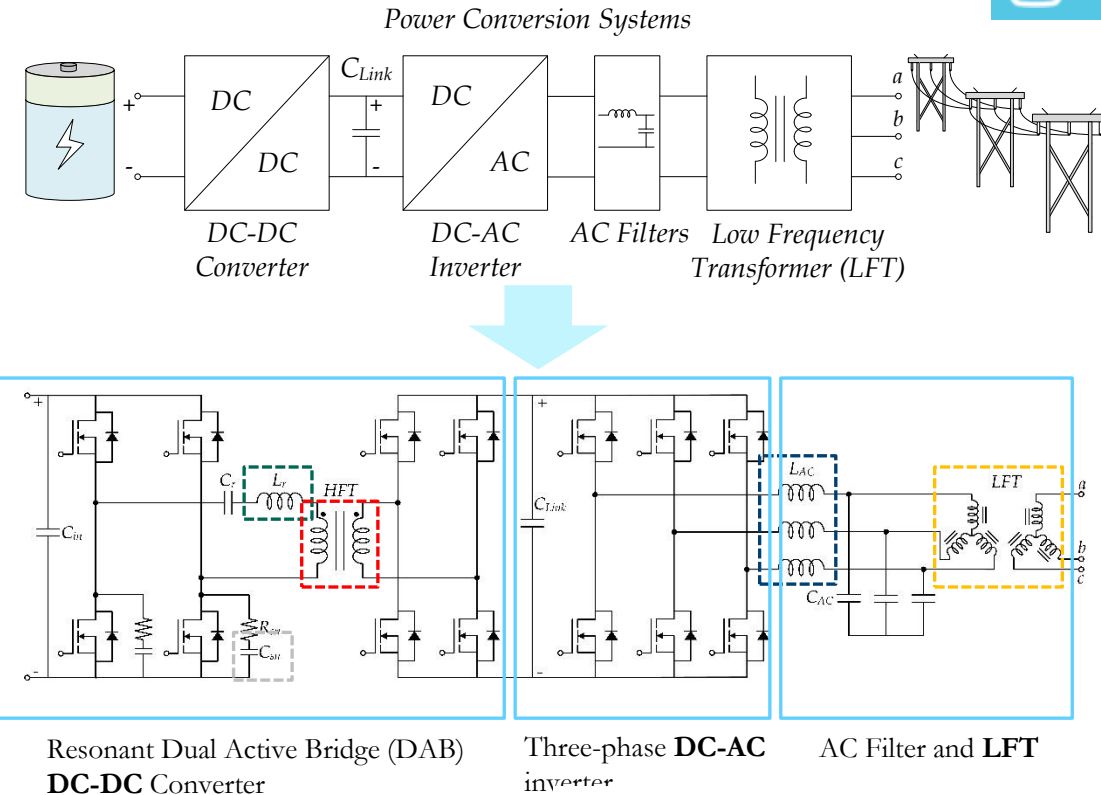
Future of semiconductors:

- Lower on-resistance for given breakdown voltage
- Higher power density and increase efficiency
- Ultra WBG, Diamond



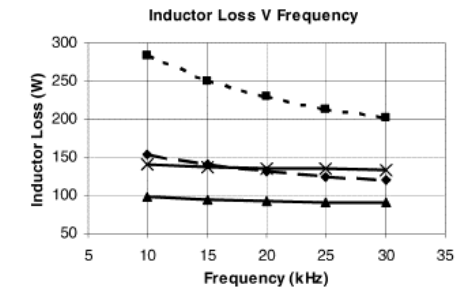
Inductors and transformers are passive elements formed by wires wound around magnetics components. Inductors store energy in an electro-magnetic field. Transformers transfer energy between primary and secondary windings wound around a magnetic material.

- Resonant inductors, L_r :
 - Forms the converter resonant tank with C_r allowing zero-voltage or zero-current switching in the DC-DC converter stage.
 - Usually L_r has a low magnitude.
- High-frequency transformer, HFT :
 - HFT allows a higher voltage conversion ratio by selecting the required turns ratio, N .
 - Compact footprint due to high frequency operation.
- AC filter inductors, L_{AC} :
 - Eliminate the harmonic distortion from the DC-AC inverter stage.
- Low-frequency transformer, LFT :
 - Step-up or down the voltage from the PCS to the required level by selecting the necessary turns ratio N .
 - LFTs are bulky since they operate at line frequency.
- Current magnetic materials do not meet all the requirements of emerging power electronics topologies.
- Significant volume reduction and increased reliability in PCS will be enabled by advanced magnetics.



Future of magnetics:

- High magnetization
- Low loss magnetic cores for high frequency transformers
- Nitrides and soft magnetic composites (SMC)
- AM 3D printed cores

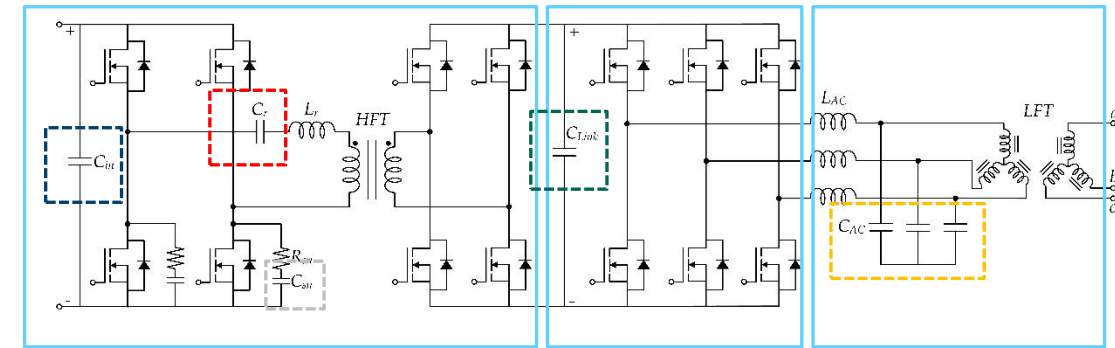
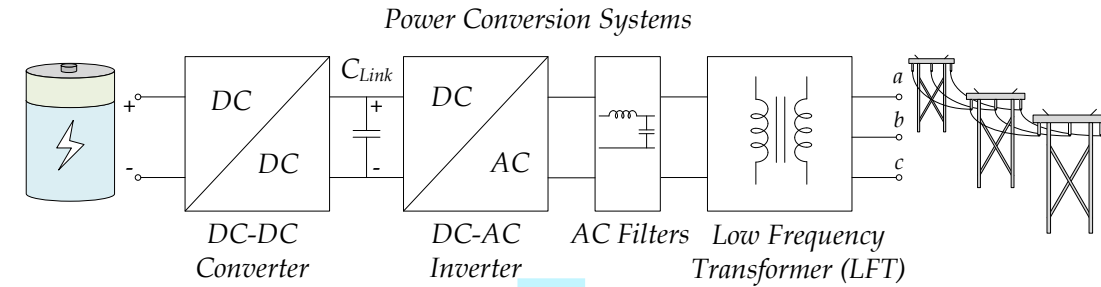


γ' -Fe₄N magnetic core

7 ROLE OF CAPACITORS IN PCS

Capacitors are passive elements that store energy in an electric field inside a dielectric material between two conductive plates.

- DC input filter capacitors, C_{in} :
 - C_{in} provides the high-frequency current demanded by the DC-DC converter.
 - Prevents battery degradation by filtering high- and low-frequency ripple currents.
- Resonant capacitor, C_r :
 - Forms the resonant tank with L_r that allows zero-voltage or zero-current switching in the DC-DC stage.
 - Usually C_r is low, but the current stress may be high.
- Snubber capacitors, C_{sn} :
 - Suppress voltage transients that may damage the semiconductor devices.
- DC link capacitors, C_{Link} :
 - DC link is an intermediate stage with a voltage level higher than the peak AC voltage level.
 - C_{link} provides a stable DC voltage and ride-through capability for a few ms in case of an interruption at AC input side.
 - Usually C_{link} is high.
- AC filter capacitors, C_{AC} :
 - Eliminate the high-frequency components from the DC-AC inverter stage.
- DC-link capacitors are prone to failure – dielectric breakdown and temperature limitations



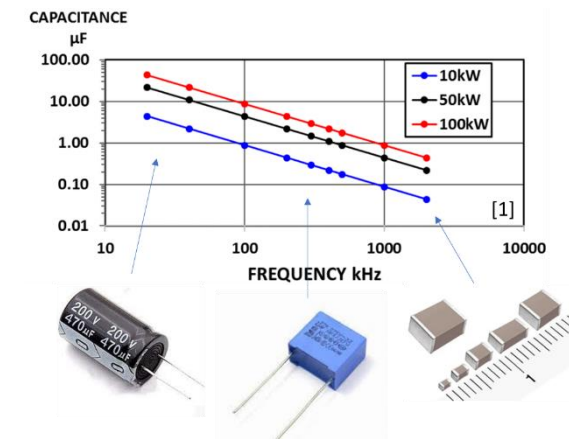
Resonant Dual Active Bridge (DAB)
DC-DC Converter

Three-phase DC-AC
inverter

AC Filter and LFT

Future of capacitors:

- High voltage
- High temperature
- Low ESL, ESR, dielectric loss
- Compact, inexpensive
- Polymer film, advanced ceramic capacitors



New components are important,
but not the whole story

Advanced Topologies:

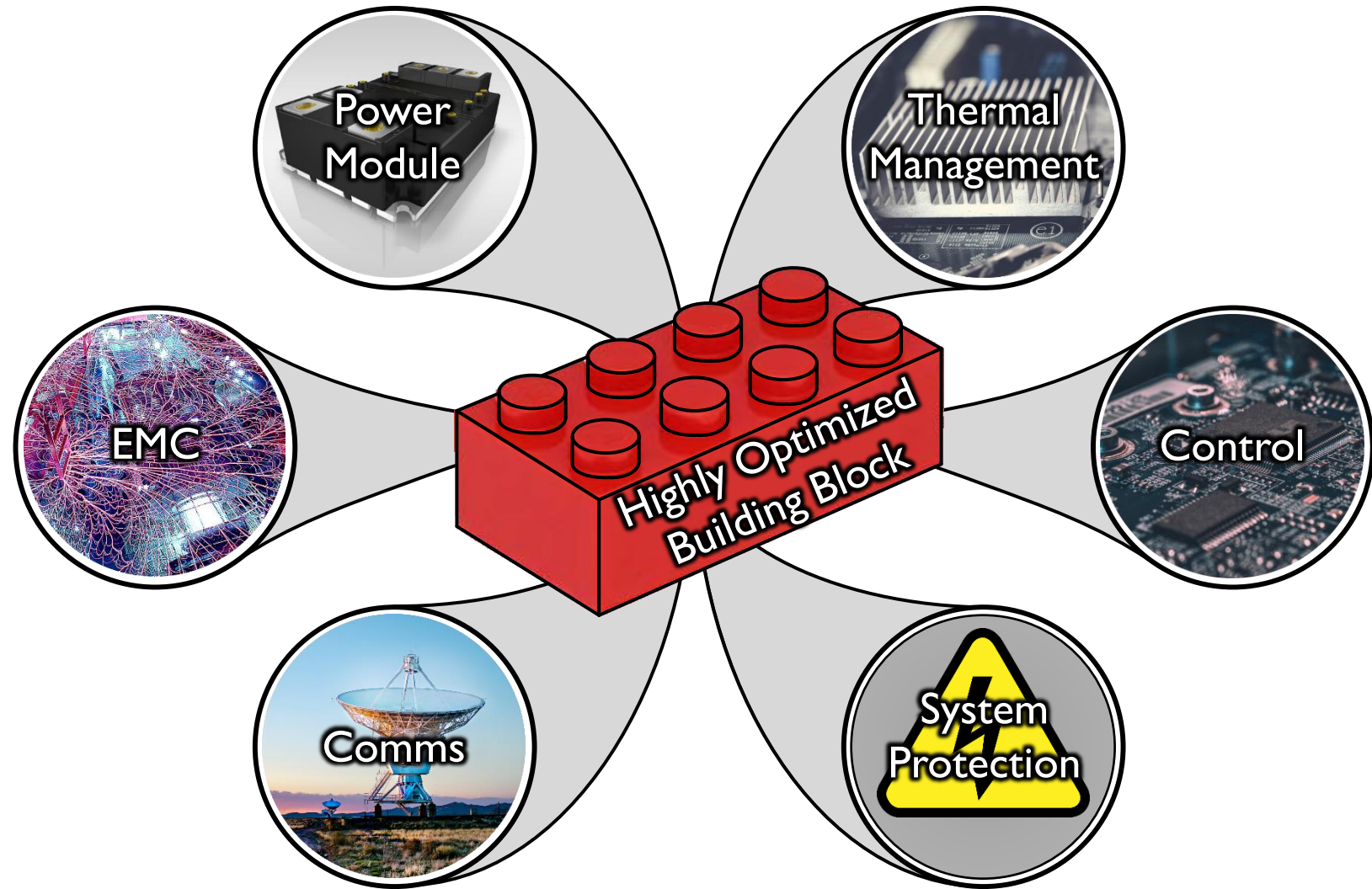
Modular, fault-tolerant hardware
architectures

Advanced Control Systems:

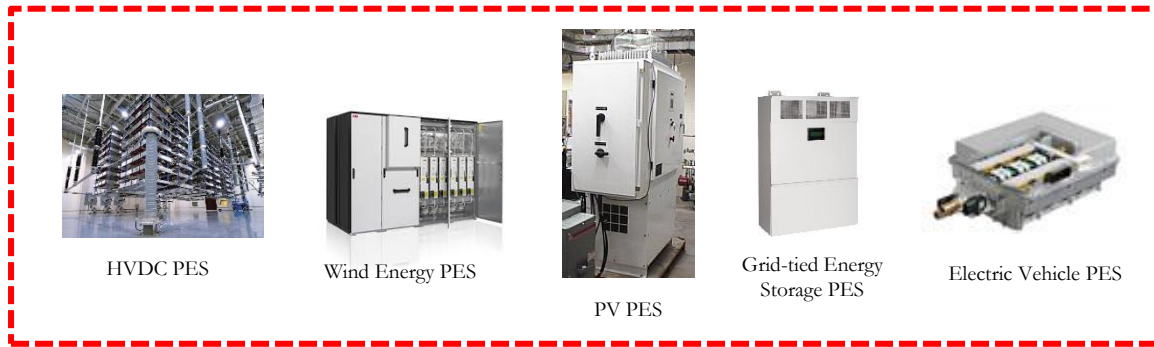
Methods for detecting and
reacting to internal failures in real
time

Design-For-Reliability:

Computational tools for
assessing reliability and remaining
time-to-failure based on
application-specific operating
conditions



POWER ELECTRONICS R&D IS HIERARICAL...



HVDC PES

Wind Energy PES

PV PES

Grid-tied Energy Storage PES

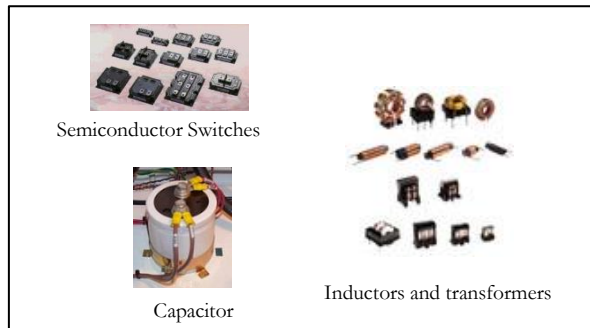
Electric Vehicle PES

Systems

- Multiple subsystems together form the system or Power Electronic System (PES)
- Self-contained, fully functional unit that performs the end-use application
- Includes DC/AC disconnects, system controls, final packaging, etc.

Components

- Materials are combined together to form components
- Basic building blocks circuit
- Includes switches, capacitors, inductors, etc.



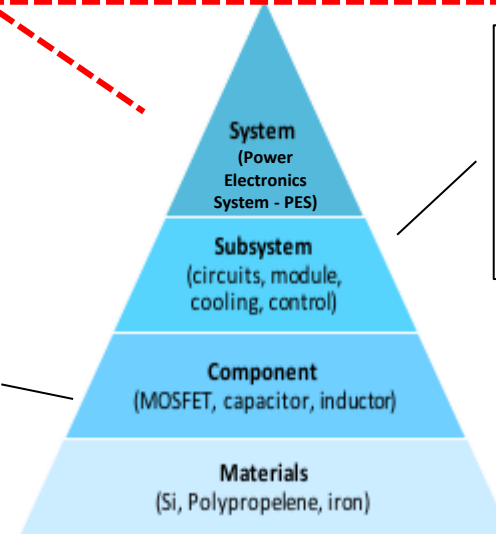
Semiconductor Switches



Capacitor

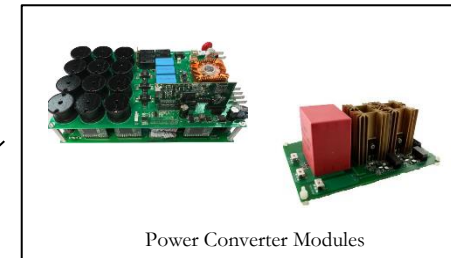


Inductors and transformers



Subsystems

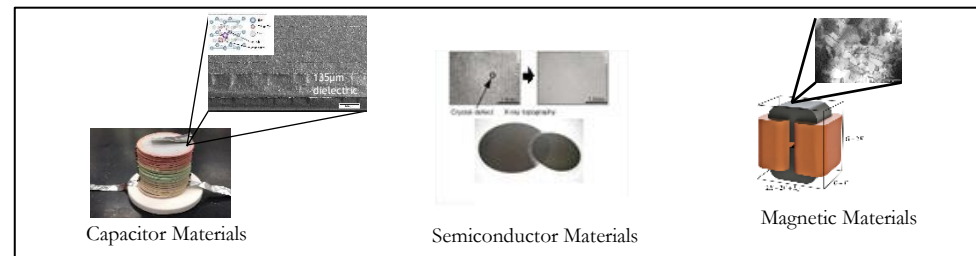
- Multiple components together form subsystems
- Perform a specific task within the PES
- Includes subsystem controls, sensors, thermal management, protection, power stage, etc.



Power Converter Modules

Materials

- Bottom layer in the PE R&D spectrum (non-application specific)
- Foundation for other technological improvements
- Advanced semiconductor, magnetic materials, new capacitor dielectrics, etc.



Capacitor Materials

Semiconductor Materials

Magnetic Materials

BATTERY ENERGY STORAGE SYSTEM ELEMENTS



Battery Storage	Battery Management System (BMS)	Power Conversion System (PCS)	Energy Management System (EMS)	Site Management System (SMS)	Balance of Plant
<ul style="list-style-type: none"> • Modules • Racks • \$/KWh 	<ul style="list-style-type: none"> • Battery Management & BESS Protection 	<ul style="list-style-type: none"> • Bi-directional Inverter • Inverter control • Interconnection / Switchgear • \$/KW 	<ul style="list-style-type: none"> • Charge / Discharge • Load Management • Ramp rate control • Grid Stability • Monitoring • \$ / ESS 	<ul style="list-style-type: none"> • Distributed Energy Resources (DER) control • Synchronization • Islanding and microgrid control • \$ / microgrid 	<ul style="list-style-type: none"> • Transformer/ POC switchgear • BESS container • Climate control • <u>Fire protection</u> • Construction and Permitting • \$ / project

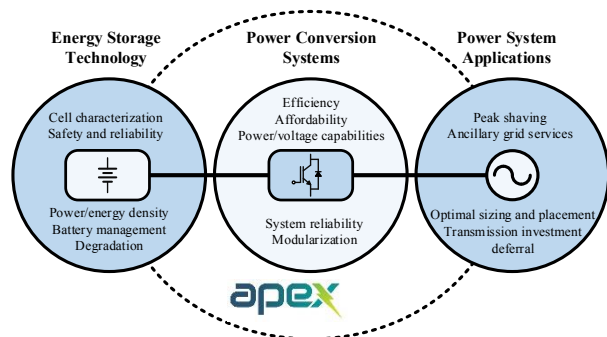


NOTE: Important to have single entity responsible for the ESS integration.



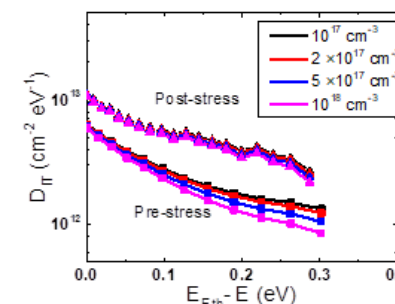
Advanced Power Electronics Conversion Systems Laboratory

- R&D of new power conversion topologies and intelligent control strategies; leverages capabilities of advanced components and materials, verifies performance through hardware experimentation



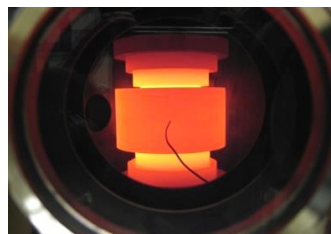
Wide Bandgap Semiconductor Characterization Laboratory

- Utilizes a range of techniques from atomic-scale characterization to reliability testing in switching circuits; stressing WBG power devices, measuring their change in performance, modeling the results, and ascertaining the impact on the PCS



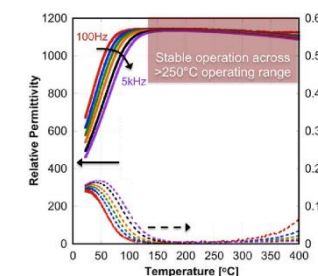
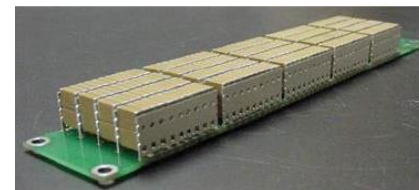
Magnetics Fabrication and Characterization Laboratory

- R&D of new high magnetization, low loss magnetic cores for high frequency converters; going beyond state-of-the-art through the implementation of iron nitride, development of new low loss soft magnetic core materials capable of operating in conjunction with WBG semiconductor-based PCS



Advanced Dielectric Laboratory

- Performs reliability assessment on commercial capacitors, understands failure physics for better reliability models, and develops next-generation capacitor materials; evaluating reliability of current generation ceramic capacitors for DC-link applications; evaluates next-gen high temperature capacitors under realistic ripple waveform seen in PCS





Ongoing Research Areas

- Power conversion system for scalable energy storage deployments
 - Modular topologies for direct MV grid connection
 - Integration of storage in existing and emerging power electronic energy infrastructure
- Uninterruptible converter topologies for critical storage assets
 - Fault-tolerant and reconfigurable hardware architectures
 - Hot-swap capable converters and storage systems
- Applications of power electronics in storage system safety
 - Stranded energy extraction
 - Active response to thermal runaway
- Integration of advanced components
 - Wide bandgap devices
 - Advanced magnetics
 - Advanced capacitors

DOE OF POWER ELECTRONICS DEVELOPMENT



WORLD'S FIRST FIBER OPTIC ELECTRICAL TRANSDUCER TO PASS MILITARY VIBRATION AND SHOCK CERTIFICATION

Exceeds 30Mhz
Capable of Operating up to 34.5kV without additional Insulation, Isolation, or Cooling



WORLD'S FIRST HIGH TEMPERATURE SiC SINGLE-PHASE INVERTER

3 kW (1200 V/150 A peak)
250 °C Junction Temperature
Integrated Gate Driver



WORLD'S FIRST HIGH TEMPERATURE SiC POWER MODULE

50 kW (1200 V/150 A peak)
250 °C Junction Temperature
Integrated HTSOI Gate Driver



WORLD'S FIRST COMMERCIALLY AVAILABLE ULTRA-HIGH-VOLTAGE SiC THYRISTOR

Rating exceed 6.5kV, 200kHz, 80A
> 200°C junction temperature



WORLD'S FIRST HIGH VOLTAGE, HIGH TEMPERATURE, REWORKABLE SiC HALF-BRIDGE POWER MODULE

> 15 kV / 100 A, > 200 °C
Reworkable
Wire Bond Free, Low Parasitic Design
Device Neutral
HV Isolated Gate Driver



WORLD'S FIRST COMMERCIAL MONOLITHIC SWITCH

1.2 kV SiC Device



GREEN
TECH
GOLD



WORLD'S HIGHEST VOLTAGE NORMALLY OFF SiC JFET

6.5 kV, 20kHz, 60A
200°C Junction Temperature



WORLD'S FIRST 3D PRINTED IRON NITRIDE AND NYLON COMPOSITE TRANSFORMER CORE

Operating temp up to 150C, 10X lower loss than bulk iron nitride, up to 1Mhz



2003

2004

2005

2006

2007

2008

2009

2010

2011

2012

2013

2014

2015

2016

2017

2018

2019

2020

2021

WORLD'S FIRST VOLTAGE CONTROLLED 4500V/400A TURN-OFF THYRISTOR

4500V and 400A rated
Integrated Si MOSFET and GTO
Embedded Current Sensing Capability



WORLD'S FIRST HIGHLY ACCELERATED LIFETIME TESTING (HALT) OF HIGH VOLTAGE SiC MODULES

Dramatically Accelerates Design Cycle
-100 °C to 250 °C (1.7 °C/s Ramp)
48 in × 48 in Table Size
6 axis 75 gRMS Vibration



WORLD'S FIRST MONOLITHICALLY INTEGRATED SINGLE CHIP TRANSISTOR

Integrated SJT/Diode Chip at 1200V



WORLD'S FIRST HIGH FREQUENCY, HIGH TEMPERATURE, SiC HALF-BRIDGE POWER MODULE

15 kV/100 A, 20 kHz, 200C
Reworkable
Low Parasitic Design
Device Neutral
HV Isolated Gate Driver



WORLD'S FIRST AVALANCHE RUGGED MULTI-KV POWER MOSFET

1 Joule at 5000V



WORLD'S FIRST HIGH POWER MODULAR GAN-BASED INVERTER

20 kW per Module
Integrated GaN Gate Driver
Stackable to 100 kW





Foli Research



TRS Technologies

Airak Corp.





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Questions?



Thank You!